

PNP Epitaxial Silicon Transistor

KSA708

Low Frequency Amplifier & Medium Speed Switching

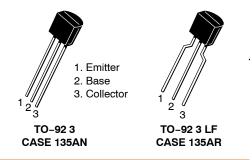
- Complement to KSC1008
- Collector-Base Voltage: $V_{CBO} = -80 \text{ V}$
- Collector Power Dissipation: $P_C = 800 \text{ mW}$
- Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)

ABSOLUTE MAXIMUM RATINGS

(T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Ratings	Unit
V _{CBO}	Collector-Base Voltage	-80	V
V _{CEO}	Collector-Emitter Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-8	V
I _C	Collector Current	-700	mA
Pc	Collector Power Dissipation	800	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



MARKING DIAGRAM

A708Y AWWY

A708Y = Specific Device Code
A = Assembly Site
WW = Work Week
Y = Year of Production

ORDERING INFORMATION

Device	Package	Shipping
KSA708YBU	TO-92 3 (Pb-Free)	10000 Units / Bulk
KSA708YTA	TO-92 3 LF (Pb-Free)	2000 Units / FNFLD

DISCONTINUED (Note 1)

KSA708CYTA	TO-923 LF	2000 Units /
	(Pb-Free)	FNFLD

 DISCONTINUED: This device is not recommended for new design. Please contact your onsemi representative for information. The most current information on this device may be available on www.onsemi.com.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -100 \mu\text{A}, \ I_E = 0$	-80	_	_	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -10 \text{ mA}, I_B = 0$	-60	_	_	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -100 \mu A, I_C = 0$	-8	_	_	V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -60 \text{ V}, I_{E} = 0$	-	_	-0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5 \text{ V}, I_{C} = 0$	-	_	-0.1	μΑ
h _{FE}	DC Current Gain*	$V_{CE} = -2 \text{ V}, I_{C} = -50 \text{ mA}$	120	_	240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage*	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$	-	-0.3	-0.7	V
V _{BE} (sat)	Base-Emitter Saturation Voltage*	$I_C = -500 \text{ mA}, I_B = -50 \text{ mA}$	-	-0.9	1.1	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -10 \text{ V}, I_{C} = -50 \text{ mA}$	-	50	ı	MHz
C _{ob}	Output Capacitance	$V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$	_	13	_	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. $*Pulse Test: PW \le 350 \ \mu s, Duty \ cycle \le 2\%.$

KSA708

TYPICAL CHARACTERISTICS

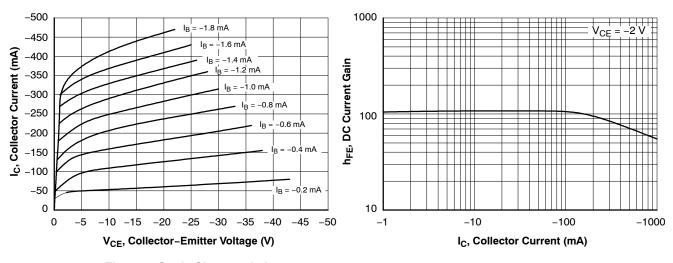


Figure 1. Static Characteristic

Figure 2. DC Current Gain

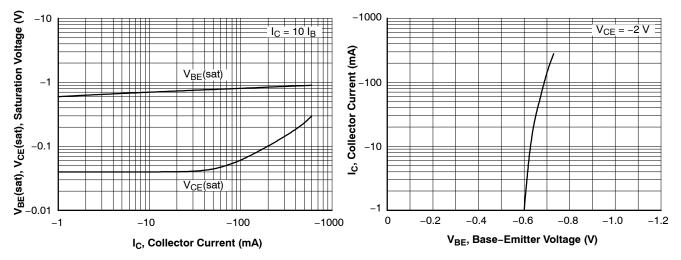


Figure 3. Base–Emitter Saturation Voltage Collector–Emitter Saturation Voltage

100

Output

O

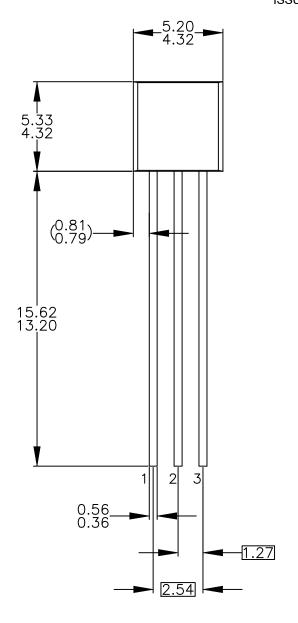
Figure 5. Collector Output Capacitance

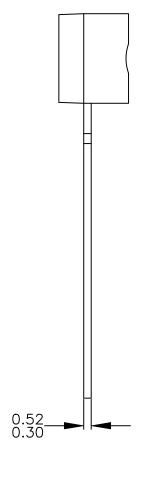
Figure 4. Base-Emitter On Voltage



TO-92 3 4.825x4.76 CASE 135AN ISSUE O

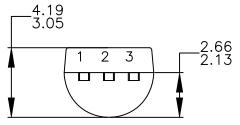
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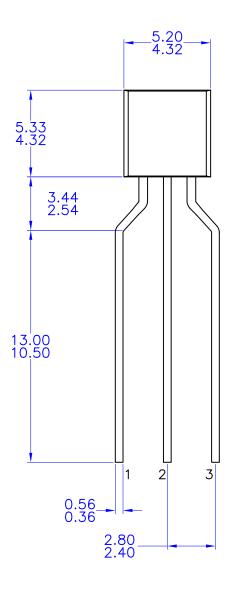
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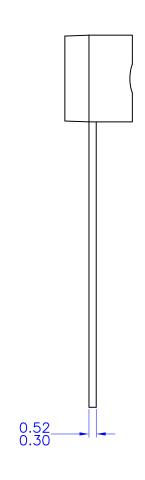


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CASE 135AR ISSUE O

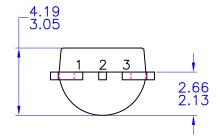
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